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ISPSD 2014 -

The International Symposium on Power Semiconductor Devices and ICs (ISPSD) companies that support the power electronics industry. The ISPSD 2014 organizing <http://ispsd.org/>

Alberto Castellazzi - The University of Nottingham -

on Power Semiconductor Devices and ICs, IEEE 10th International Conference on Power IEEE International Symposium on Power <http://www.nottingham.ac.uk/research/groups/power-electronics-machines-and-control-group/people/alberto.castellazzi>

Patent US8026588 - Method of wire bonding over -

Performance characteristics of semiconductor devices are Technology Symposium, Japan " Proceedings of the 10th International IEEE VLSI <http://www.google.com.mx/patents/US8026588>

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Patent US8168527 - Semiconductor chip and method -

and impurities can be prevented from penetrating through the passivation layer 34 to the semiconductor devices signals or to be connected to a power source <http://www.google.co.zw/patents/US8168527>

Rank of Keywords of International Conferences on -

international symposium on power semiconductor devices: 2 10th ieee international conference on computer and japan international symposium on august <http://www.ourglocal.com/keywords/?date=20110625>

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GIOVANNI BUSATTO - Universit degli Studi di -

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Invited Talks Gaudenzio Meneghesso -

He has been personally invited to give 42 INVITED TALKS: on Power Semiconductor Devices and ICs IEEE International Symposium on Power

<http://www.meneghesso.it/en/pubblications/recent-publications/>

Resume: Yung C. Liang - National University of -

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Publications by Prof. Florin Udrea | Department of -

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Kenya Kobayashi | LinkedIn -

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